

To our customers,

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## Old Company Name in Catalogs and Other Documents

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April 1<sup>st</sup>, 2010  
Renesas Electronics Corporation

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# SILICON POWER TRANSISTOR

## 2SA1010

### PNP SILICON EPITAXIAL TRANSISTOR FOR HIGH-VOLTAGE HIGH-SPEED SWITCHING

The 2SA1010 is a mold power transistor developed for high-voltage high-speed switching, and is ideal for use as a driver in devices such as switching regulators, DC/DC converters, and high-frequency power amplifiers.

#### FEATURES

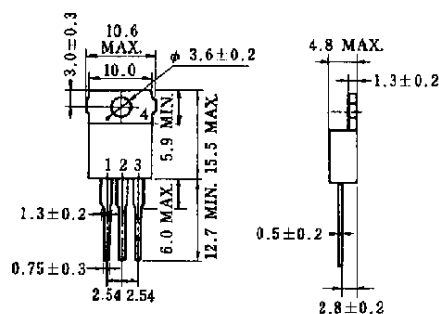
- Low collector saturation voltage
- Fast switching speed
- Complementary transistor: 2SC2334

#### ABSOLUTE MAXIMUM RATINGS (Ta = 25°C)

| Parameter                    | Symbol             | Ratings     | Unit |
|------------------------------|--------------------|-------------|------|
| Collector to base voltage    | $V_{CBO}$          | -100        | V    |
| Collector to emitter voltage | $V_{CEO}$          | -100        | V    |
| Emitter to base voltage      | $V_{EBO}$          | -7.0        | V    |
| Collector current (DC)       | $I_{C(DC)}$        | -7.0        | A    |
| Collector current (pulse)    | $I_{C(pulse)}^*$   | -15         | A    |
| Base current (DC)            | $I_{B(DC)}$        | -3.5        | A    |
| Total power dissipation      | $P_T$ (Tc = 25 °C) | 40          | W    |
| Total power dissipation      | $P_T$ (Ta = 25 °C) | 1.5         | W    |
| Junction temperature         | $T_j$              | 150         | °C   |
| Storage temperature          | $T_{stg}$          | -55 to +150 | °C   |

\* PW ≤ 300 μs, duty cycle ≤ 10%

#### PACKAGE DRAWING (UNIT: mm)



#### Pin Connection

1. Base
2. Collector
3. Emitter
4. Fin (Collector)

EIAJ : SC-46  
JEDEC : TO-220AB  
IEC : —

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**ELECTRICAL CHARACTERISTICS (Ta = 25°C)**

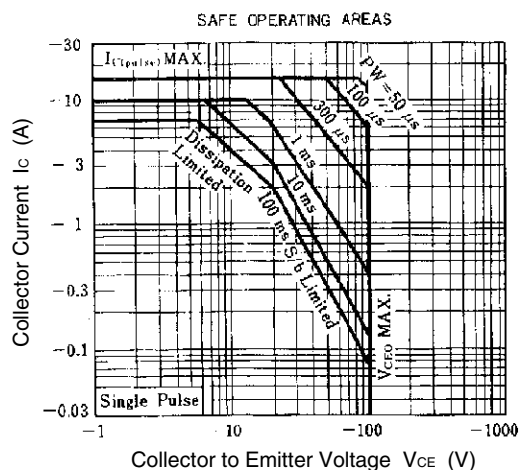
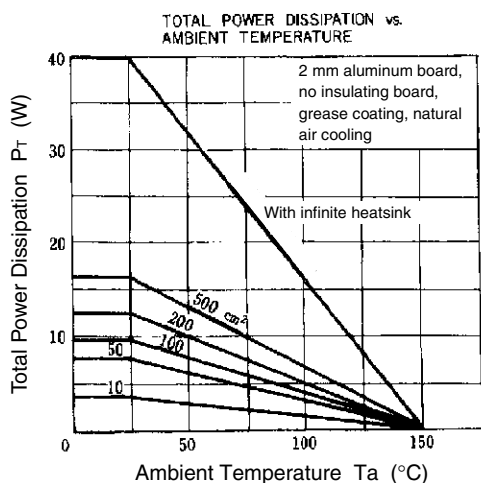
| Parameter                    | Symbol          | Conditions                                                                                                                                            | MIN. | TYP. | MAX. | Unit          |
|------------------------------|-----------------|-------------------------------------------------------------------------------------------------------------------------------------------------------|------|------|------|---------------|
| Collector to emitter voltage | $V_{CE0(SUS)}$  | $I_C = -5.0\text{ A}$ , $I_{B1} = -0.5\text{ A}$ , $L = 1\text{ mH}$                                                                                  | -100 |      |      | V             |
| Collector to emitter voltage | $V_{CEX(SUS)1}$ | $I_C = -5.0\text{ A}$ , $I_{B1} = -I_{B2} = -0.5\text{ A}$ ,<br>$V_{BE(OFF)} = 5.0\text{ V}$ , $L = 180\text{ }\mu\text{H}$ , clamped                 | -100 |      |      | V             |
| Collector to emitter voltage | $V_{CEX(SUS)2}$ | $I_C = -10\text{ A}$ , $I_{B1} = -1.0\text{ A}$ , $I_{B2} = -0.5\text{ A}$ ,<br>$V_{BE(OFF)} = 5.0\text{ V}$ , $L = 180\text{ }\mu\text{H}$ , clamped | -100 |      |      | V             |
| Collector cutoff current     | $I_{CBO}$       | $V_{CB} = -100\text{ V}$ , $I_E = 0$                                                                                                                  |      |      | -10  | $\mu\text{A}$ |
| Collector cutoff current     | $I_{CER}$       | $V_{CE} = -100\text{ V}$ , $R_{BE} = 51\text{ }\Omega$ , $T_a = 125\text{ }^\circ\text{C}$                                                            |      |      | -1.0 | mA            |
| Collector cutoff current     | $I_{CEX1}$      | $V_{CE} = -100\text{ V}$ , $V_{BE(OFF)} = 1.5\text{ V}$                                                                                               |      |      | -10  | $\mu\text{A}$ |
| Collector cutoff current     | $I_{CEX2}$      | $V_{CE} = -100\text{ V}$ , $V_{BE(OFF)} = 1.5\text{ V}$ ,<br>$T_a = 125\text{ }^\circ\text{C}$                                                        |      |      | -1.0 | mA            |
| Emitter cutoff current       | $I_{EBO}$       | $V_{EB} = -5.0\text{ V}$ , $I_C = 0$                                                                                                                  |      |      | -10  | $\mu\text{A}$ |
| DC current gain              | $h_{FE1}$       | $V_{CE} = -5.0\text{ V}$ , $I_C = -0.5\text{ A}^*$                                                                                                    | 40   |      | 200  |               |
| DC current gain              | $h_{FE2}$       | $V_{CE} = -5.0\text{ V}$ , $I_C = -3.0\text{ A}^*$                                                                                                    | 40   |      | 200  |               |
| DC current gain              | $h_{FE3}$       | $V_{CE} = -5.0\text{ V}$ , $I_C = -5.0\text{ A}^*$                                                                                                    | 20   |      |      |               |
| Collector saturation voltage | $V_{CE(sat)}$   | $I_C = -5.0\text{ A}$ , $I_B = -0.5\text{ A}^*$                                                                                                       |      |      | -0.6 | V             |
| Base saturation voltage      | $V_{BE(sat)}$   | $I_C = -5.0\text{ A}$ , $I_B = -0.5\text{ A}^*$                                                                                                       |      |      | -1.5 | V             |
| Turn-on time                 | $t_{on}$        | $I_C = -5.0\text{ A}$ , $R_L = 10\text{ }\Omega$ ,<br>$I_{B1} = -I_{B2} = -0.5\text{ A}$ , $V_{CC} \cong -50\text{ V}$<br>Refer to the test circuit.  |      |      | 0.5  | $\mu\text{s}$ |
| Storage time                 | $t_{stg}$       |                                                                                                                                                       |      |      | 1.5  | $\mu\text{s}$ |
| Fall time                    | $t_f$           |                                                                                                                                                       |      |      | 0.5  | $\mu\text{s}$ |

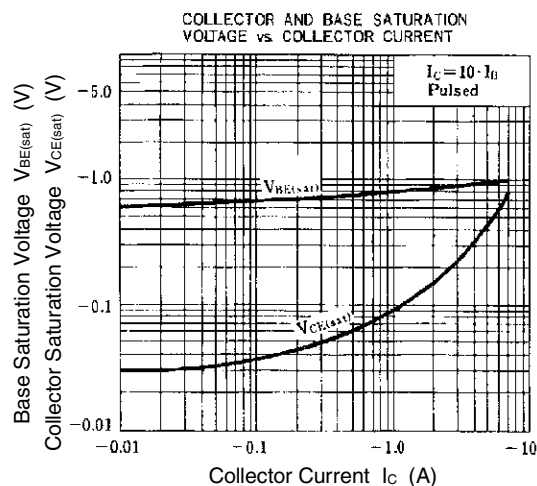
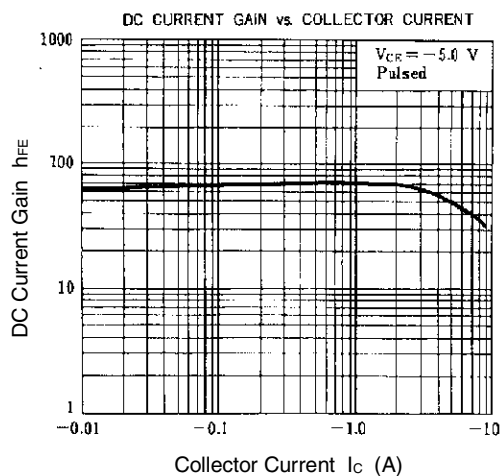
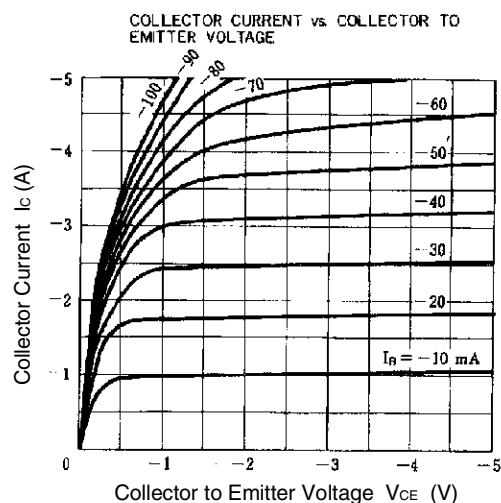
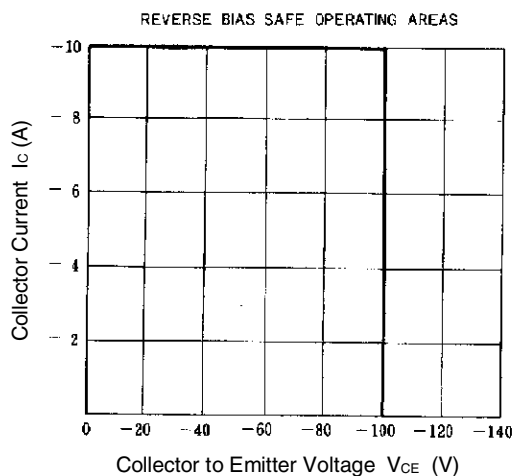
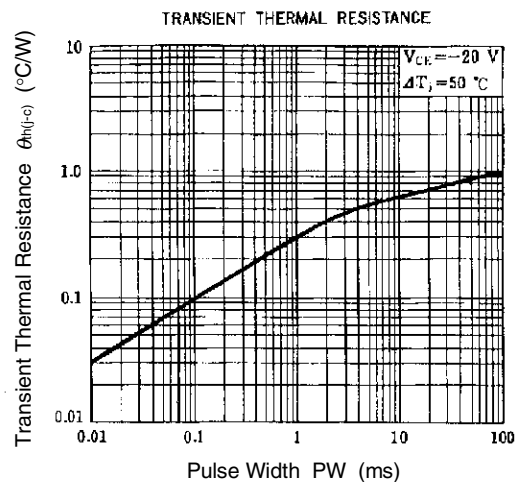
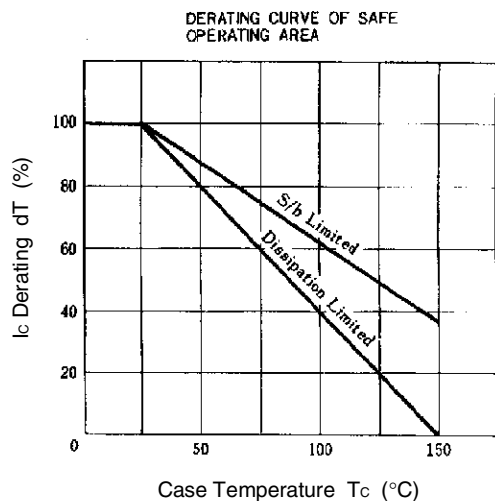
\* Pulse test  $PW \leq 350\text{ }\mu\text{s}$ , duty cycle  $\leq 2\%$

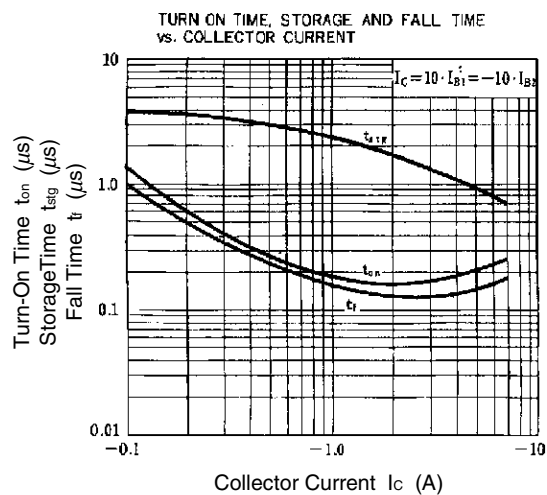
**$h_{FE}$  CLASSIFICATION**

| Marking   | M        | L         | K          |
|-----------|----------|-----------|------------|
| $h_{FE2}$ | 40 to 80 | 60 to 120 | 100 to 200 |

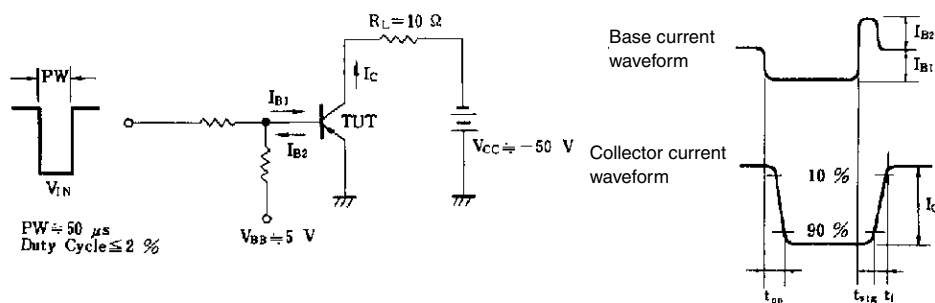
**TYPICAL CHARACTERISTICS (Ta = 25°C)**







SWITCHING TIME ( $t_{on}$ ,  $t_{stg}$ ,  $t_f$ ) TEST CIRCUIT



[MEMO]

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